











DS90LT012AH

ZHCSJ96B - SEPTEMBER 2005 - REVISED JANUARY 2019

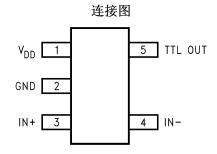
# DS90LT012AH 高温 3V LVDS 差动线路接收器

### 1 特性

- -40°C 至 +125°C 温度范围工作
- 符合 ANSI TIA/EIA-644-A 标准
- >400Mbps (200MHz) 开关速率
- 100ps 差动偏斜(典型值)
- 3.5ns 最大传播延迟
- 集成线路端接电阻(100Ω 典型值)
- 单通道 3.3V 电源设计(2.7V 至 3.6V 范围)
- 在断电模式下, LVDS 输入端具有高阻抗
- LVDS 输入可接受 LVDS/CML/LVPECL 信号
- 引脚简化了 PCB 布局
- 低功率耗散(3.3V静态条件下为典型值 10mW)
- 5 引脚小外形尺寸晶体管 (SOT)-23 封装

#### 2 应用

- 板对板通信
- 测试和测量
- LED 视频墙
- 电机驱动器
- 无线基础设施
- 电信基础设施
- 多功能打印机
- NIC卡
- 机架式服务器
- 超声波扫描仪



### 3 说明

DS90LT012AH 器件是一款单路 CMOS 差动线路接收器,专为需要超低功率耗散、低噪声和高数据速率的应用而设计。该器件旨在使用低电压差动摆幅 (LVDS) 技术支持超过 400Mbps (200MHz) 的数据速率。

DS90LT012AH 接受低电压(350mV 典型值)差动输入信号,并将其转换为 3V CMOS 输出电平。

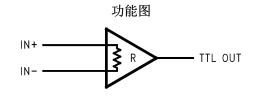
DS90LT012AH 包含应用于点对点应用的 输入线路终端电阻器。

DS90LT012AH 和配套的 LVDS 线路驱动器 DS90LV011AH 为高速接口应用提供了高功率 PECL/ECL 器件的全新替代 产品。

#### 器件信息(1)

器件型号	封装	封装尺寸 (标称值)		
DS90LT012AH	SOT-23 (5)	2.90mm × 1.60mm		

(1) 如需了解所有可用封装,请参阅数据表末尾的可订购产品附录。





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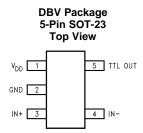
# 4 修订历史记录

注: 之前版本的页码可能与当前版本有所不同。

CI	hanges from Revision A (April 2013) to Revision B	Page
•	已删除数据表中的 NRND 免责声明	1
•	已将数据表的文本和格式更改为 TI 最新的文档标准	1
•	Moved the ESD Ratings to the ESD Ratings table	4
•	Changed and moved thermal resistance ( $\theta_{JA}$ ) parameter in the <i>Absolute Maximum Ratings</i> table to the <i>Thermal Information</i> table	4
•	Removed the duplicate <i>Truth Table</i> that shared the same information found in the <i>DS90LT012AH Receiver Function</i> table	8
CI	hanges from Original (April 2013) to Revision A	Page
•	已将美国国家半导体数据表的版面布局更改为 TI 格式	1



# **5 Pin Configuration and Functions**



### **Pin Functions**

PIN		1/0	DESCRIPTION			
NAME	NO.	I/O	DESCRIPTION			
VDD	1	I	Power supply pin, +3.3 V ± 0.3 V			
GND	2	I	Ground pin			
IN+	3	1	Non-inverting reciever input pin			
IN-	4	I	Inverting reciever input pin			
TTL OUT 5 O		0	LVTTL/LVCMOS reciever output pin			



### 6 Specifications

### 6.1 Absolute Maximum Ratings (1)

	5	MIN	MAX	UNIT	
Supply Voltage (V <sub>DD</sub> )	put Voltage (IN+, IN-) put Voltage (TTL OUT) put Short Circuit Current rimum Package Power Dissipation at  DBV Package				
Input Voltage (IN+, IN-)		-0.3	3.9	V	
Output Voltage (TTL OUT)	-0.3	$V_{DD} + 0.3$	V		
Output Short Circuit Current		-100	mA		
Maximum Package Power Dissipation at	DBV Package		902	mW	
+25°C	OUT)	mW/°C			
Lead Temperature Range Soldering	(4 sec.)		260	°C	
Maximum Junction Temperature		150	°C		
Storage Temperature, T <sub>stg</sub>		-65	150	°C	

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 $^{(1)}$ (1.5 k $\Omega$ , 100 pF)	2000	
\/	Electrostatic discharge Charged-device model (CDM), per JEDEC specification $EIAJ (0 \Omega, 200 pF)$ IEC direct (330 $\Omega$ , 150 pF)	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)		\/
V <sub>(ESD)</sub>		EIAJ (0 Ω, 200 pF)	700	V
		IEC direct (330 $\Omega$ , 150 pF)	7000	

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Pins listed as ±XXX V may actually have higher performance.

### 6.3 Recommended Operating Conditions

	MIN	TYP	MAX	UNIT
Supply Voltage (V <sub>DD</sub> )	+2.7	+3.3	+3.6	V
Ambient Temperature (T <sub>A</sub> )	-40	25	+125	°C
Junction Temperature (T <sub>(J)</sub>			+130	°C

#### 6.4 Thermal Information

	DS90LT012AH					
	THERMAL METRIC <sup>(1)</sup>	DBV (SOT-23)	UNIT			
		5 PINS				
$R_{\theta JA}$	Junction-to-ambient thermal resistance	179	°C/W			
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	105.5	°C/W			
$R_{\theta JB}$	Junction-to-board thermal resistance	44.7	°C/W			
ΨЈТ	Junction-to-top characterization parameter	20.4	°C/W			
ΨЈВ	Junction-to-board characterization parameter	44.4	°C/W			

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

#### 6.5 Electrical Characteristics

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified. (1) (2)

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Pins listed as ±2000 V may actually have higher performance.

Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground unless otherwise specified (such as V<sub>ID</sub>).

<sup>(2)</sup> All typicals are given for:  $V_{DD} = +3.3 \text{ V}$  and  $T_A = +25^{\circ}\text{C}$ .



### **Electrical Characteristics (continued)**

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified. (1) (2)

	PARAMETER	TEST CONDITIONS	PIN	MIN	TYP	MAX	UNIT
$V_{TH}$	Differential Input High Threshold	V dependent on V (3)			-30	0	mV
$V_{TL}$	Differential Input Low Threshold	$V_{CM}$ dependant on $V_{DD}^{(3)}$ $V_{DD} = 2.7 \text{ V}, V_{ID} = 100 \text{ mV}$ $V_{DD} = 3 \text{ V} \text{ to } 3.6 \text{ V}, V_{ID} = 100 \text{ mV}$		-100	-30		mV
		$V_{DD} = 2.7 \text{ V}, V_{ID} = 100 \text{ mV}$		0.05		2.35	V
$V_{\text{CM}}$	Common-Mode Voltage	$V_{DD} = 3 \text{ V to } 3.6 \text{ V}, V_{ID} = 100 \text{ mV}$		0.05		$V_{DD} - 0.3$	V
		T <sub>A</sub> = 125°C		0.1		2.35	V
		$V_{IN} = +2.8 \text{ V}$		-10	±1	+10	μΑ
$I_{\text{IN}}$	Input Current (DS90LV012A)	$V_{IN} = 0 \text{ V}$ $V_{DD} = 3.6 \text{ V or } 0 \text{ V}$		-10	±1	+10	μΑ
		$V_{IN} = +3.6 \text{ V}$ $V_{DD} = 0 \text{ V}$	IN+, IN−	-20		+20	μΑ
$\Delta I_{\text{IN}}$	Change in Magnitude of I <sub>IN</sub>	$V_{IN} = +2.8 \text{ V}$			4		μΑ
		$V_{IN} = 0 \text{ V}$ $V_{DD} = 3.6 \text{ V or } 0 \text{ V}$			4		μΑ
		$V_{IN} = +3.6 \text{ V}$ $V_{DD} = 0 \text{ V}$			4		μΑ
	Differential Innert Comment	V <sub>IN+</sub> = +0.4 V, V <sub>IN-</sub> = +0 V		3	3.9	4.4	A
I <sub>IND</sub>	Differential Input Current	$V_{IN+} = +2.4 \text{ V}, V_{IN-} = +2.0 \text{ V}$		3	3.9	4.4	mA
$R_{T}$	Integrated Termination Resistor				100		Ω
C <sub>IN</sub>	Input Capacitance	IN+ = IN− = GND			3		pF
		$I_{OH} = -0.4 \text{ mA}, V_{ID} = +200 \text{ mV}$		2.4	3.1		V
$V_{OH}$	Output High Voltage	$I_{OH} = -0.4$ mA, Inputs terminated		2.4	3.1		V
		I <sub>OH</sub> = −0.4 mA, Inputs shorted	TTL OUT	2.4	3.1		V
$V_{OL}$	Output Low Voltage	$I_{OL} = 2 \text{ mA}, V_{ID} = -200 \text{ mV}$	1112 001		0.3	0.5	V
los	Output Short-Circuit Current	V <sub>OUT</sub> = 0V <sup>(4)</sup>		-15	-50	-100	mA
$V_{CL}$	Input Clamp Voltage	I <sub>CL</sub> = −18 mA		-1.5	-0.7		V
I <sub>DD</sub>	No Load Supply Current	Inputs Open	$V_{DD}$		5.4	9	mA

V<sub>DD</sub> is always higher than IN+ and IN− voltage. IN+ and IN− are allowed to have voltage range −0.05 V to +2.35 V when V<sub>DD</sub> = 2.7 V and  $|V_{ID}|$  /2 to  $|V_{DD}| = 0.3$  V when  $|V_{DD}| = 3.0$  V to 3.6 V.  $|V_{ID}|$  is not allowed to be greater than 100 mV when  $|V_{CM}| = 0.05$  V to 2.35 V when  $|V_{DD}| = 2.7$  V or when  $|V_{CM}| = |V_{ID}|$  /2 to  $|V_{DD}| = 0.3$  V when  $|V_{DD}| = 3.0$  V to 3.6 V. (4) Output short-circuit current ( $|V_{CM}| = |V_{ID}|$ ) is specified as magnitude only, minus sign indicates direction only. Only one output should be shorted

#### 6.6 Switching Characteristics

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified. (1) (2)

	PARAMETER		MIN	TYP	MAX	UNIT
t <sub>PHLD</sub>	Differential Propagation Delay High to Low		1	1.8	3.5	ns
t <sub>PLHD</sub>	Differential Propagation Delay Low to High		1	1.7	3.5	ns
t <sub>SKD1</sub>	Differential Pulse Skew  t <sub>PHLD</sub> - t <sub>PLHD</sub>   (3)		0	100	400	ps
t <sub>SKD3</sub>	Differential Part to Part Skew (4)	$C_L = 15 \text{ pF}$ $V_{ID} = 200 \text{ mV}$	0	0.3	1.0	ns
t <sub>SKD4</sub>	Differential Part to Part Skew (5)	V <sub>ID</sub> = 200 mV (Figure 9 and Figure 10)	0	0.4	1.5	ns
t <sub>TLH</sub>	Rise Time	( rigare a arra rigare re,		350	800	ps
t <sub>THL</sub>	Fall Time			175	800	ps
f <sub>MAX</sub>	Maximum Operating Frequency (6)		200	250		MHz

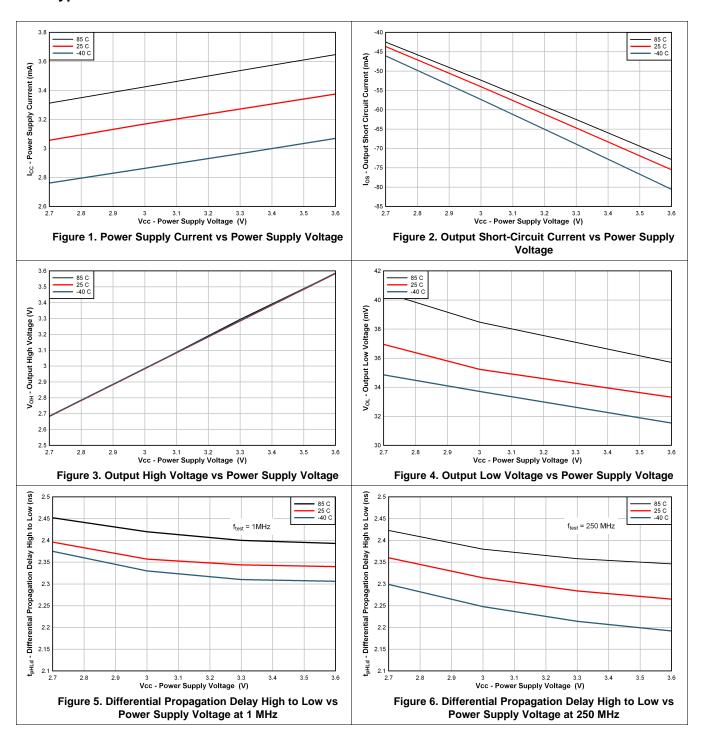
C<sub>L</sub> includes probe and jig capacitance. (1)

- Generator waveform for all tests unless otherwise specified: f = 1 MHz,  $Z_O = 50 \Omega$ ,  $t_r$  and  $t_f$  (0% to 100%)  $\leq 3 \text{ ns}$  for IN±.
- t<sub>SKD1</sub> is the magnitude difference in differential propagation delay time between the positive-going-edge and the negative-going-edge of the same channel.
- t<sub>SKD3</sub>, part to part skew, is the differential channel-to-channel skew of any event between devices. This specification applies to devices at the same V<sub>DD</sub> and within 5°C of each other within the operating temperature range.
- t<sub>SKD4</sub>, part to part skew, is the differential channel-to-channel skew of any event between devices. This specification applies to devices over the recommended operating temperature and voltage ranges, and across process distribution. t<sub>SKD4</sub> is defined as |Max - Min| differential propagation delay.
- $f_{\text{MAX}}$  generator input conditions:  $t_r = t_f < 1$  ns (0% to 100%), 50% duty cycle, differential (1.05 V to 1.35 peak to peak). Output criteria: 60%/40% duty cycle,  $V_{\text{OL}}$  (max 0.4 V),  $V_{\text{OH}}$  (min 2.4 V), load = 15 pF (stray plus probes). The parameter is specified by design. The limit is based on the statistical analysis of the device over the PVT range by the transition times (t<sub>TLH</sub> and t<sub>THL</sub>).

at a time, do not exceed maximum junction temperature specification.

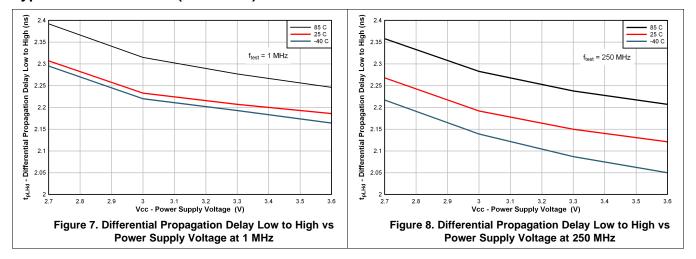
### TEXAS INSTRUMENTS

### 6.7 Typical Characteristics





### **Typical Characteristics (continued)**



### 7 Parameter Measurement Information

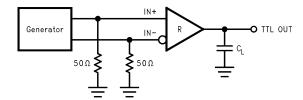


Figure 9. Receiver Propagation Delay and Transition Time Test Circuit

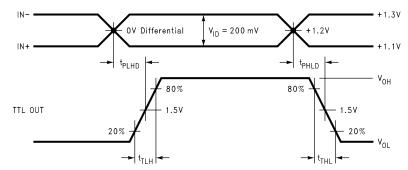


Figure 10. Receiver Propagation Delay and Transition Time Waveforms



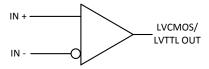
### 8 Detailed Description

#### 8.1 Overview

The DS90LT012AH is a single-channel, low-voltage differential signaling (LVDS) line receiver. It operates from a single power supply that is nominally 3.3 V, but the supply can be as low as 3 V and as high as 3.6 V. The input to the DS90LT012AH is a differential signal complying with the LVDS Standard (TIA/EIA-644), and the output is a 3.3-V LVCMOS/LVTTL signal. The differential input signal operates with a signal level of 340 mV, nominally, at a common-mode voltage of 1.2 V. The differential nature of the inputs provides immunity to common-mode coupled signals that the driven signal may experience. A termination resistor of 100  $\Omega$  is intergrated into DS90LT012AH.

LVDS receivers are intended to be primarily used in an point-to-point configuration. This configuration provides a clean signaling environment for the fast edge rates of the drivers. The receiver is connected to the driver through a balanced media which may be a standard twisted-pair cable, a parallel pair cable, or simply PCB traces. Typically the characteristic impedance of the media is in the range of  $100~\Omega$ . The intergrated termination resistor converts the driver output (current mode) into a voltage without the need for external termination and is detected by the receiver. Other configurations are possible such as a multi-receiver configuration, but the effects of a midstream connector(s), cable stub(s), and other impedance discontinuities as well as ground shifting, noise margin limits, and total termination loading must be taken into account.

#### 8.2 Functional Block Diagram



#### 8.3 Feature Description

The DS90LT012AH is capable of detecting signals as low as 100 mV, over a  $\pm 1$ -V common-mode range centered around 1.2 V. The AC parameters of the input pins are optimized for a recommended operating input voltage range of 0 V to 2.4 V (measured from each pin to ground). The device will operate for receiver input voltages up to  $V_{DD}$ , but exceeding  $V_{DD}$  will turn on the ESD protection circuitry which will clamp the bus voltages.

Table 1. DS90LT012AH Receiver Function

INPUTS	OUTPUT
V <sub>ID</sub> = [IN+] − [IN−]	TTL OUT
V <sub>ID</sub> ≥ 0 V	Н
V <sub>ID</sub> ≤ −0.1 V	L
Full Fail-safe OPEN/SHORT or Terminated	Н

#### 8.3.1 Termination

DS90LT012AH integrates the terminating resistor for point-to-point applications. The resistor value will be between 90  $\Omega$  and 133  $\Omega$ .

### 8.3.2 Threshold

The LVDS Standard (ANSI/TIA/EIA-644-A) specifies a maximum threshold of  $\pm 100$  mV for the LVDS receiver. The DS90LT012AH supports an enhanced threshold region of -100 mV to 0 V. This is useful for fail-safe biasing. The threshold region is shown in the Voltage Transfer Curve (VTC) in Figure 11. The typical DS90LT012AH LVDS receiver switches at about -30 mV. Note that with  $V_{ID} = 0$  V, the output will be in a HIGH state. With an external fail-safe bias of +25 mV applied, the typical differential noise margin is now the difference from the switch point to the bias point. In the example shown in Figure 11, this would be 55 mV of Differential Noise



Margin (DNM) (+25 mV - (-30 mV)). With the enhanced threshold region of -100 mV to 0 V, this small external fail-safe biasing of +25 mV (with respect to 0 V) gives a DNM of a comfortable 55 mV. With the standard threshold region of ±100 mV, the external fail-safe biasing must be +25 mV with respect to +100 mV or +125 mV, giving a DNM of 155 mV that is a stronger fail-safe biasing than necessary for the DS90LT012AH. If more DNM is required, then a stronger fail-safe bias point can be set by changing resistor values.

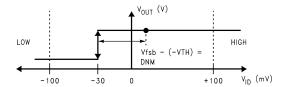


Figure 11. VTC of the DS90LT012AH LVDS Receiver

#### 8.3.3 Fail-Safe Feature

The LVDS receiver is a high-gain, high-speed device that amplifies a small differential signal (20 mV) to LVCMOS/LVTTL logic levels. Due to the high gain and tight threshold of the receiver, take care to prevent noise from appearing as a valid signal.

The receiver's internal fail-safe circuitry is designed to source/sink a small amount of current, providing fail-safe protection (a stable known state of HIGH output voltage) for floating, terminated, or shorted receiver inputs.

- 1. **Open Input Pins:** It is not required to tie the receiver inputs to ground or any supply voltage. Internal failsafe circuitry will ensure a HIGH, stable output state for open inputs.
- 2. **Terminated Input:** If the driver is disconnected (cable unplugged), or if the driver is in a power-off condition, the receiver output will again be in a HIGH state, even with the end cable 100-Ω termination resistor across the input pins. The unplugged cable can become a floating antenna which can pick up noise. If the cable picks up more than 10 mV of differential noise, the receiver may see the noise as a valid signal and switch. To insure that any noise is seen as common-mode and not differential, a balanced interconnect should be used. A twisted-pair cable will offer better balance than flat ribbon cable.
- 3. **Shorted Inputs:** If a fault condition occurs that shorts the receiver inputs together, thus resulting in a 0-V differential input voltage, the receiver output will remain in a HIGH state. Shorted input fail-safe is not supported across the common-mode range of the device (GND to 2.4 V). It is only supported with inputs shorted and no external common-mode voltage applied.

External lower value pullup and pulldown resistors (for a stronger bias) may be used to boost fail-safe in the presence of higher noise levels. The pullup and pulldown resistors should be in the  $5-k\Omega$  to  $15-k\Omega$  range to minimize loading and waveform distortion to the driver. The common-mode bias point should be set to approximately 1.2 V (less than 1.75 V) to be compatible with the internal circuitry.

The DS90LT012AH is compliant to the original ANSI EIA/TIA-644 specification and is also compliant to the new ANSI EIA/TIA-644-A specification with the exception of the newly added  $\Delta I_{IN}$  specification. Due to the internal fail-safe circuitry,  $\Delta I_{IN}$  cannot meet the 6- $\mu$ A maximum specified. This exception will not be relevant unless more than 10 receivers are used.

Additional information on the fail-safe biasing of LVDS devices may be found in *AN-1194 Failsafe Biasing of LVDS Interfaces* (SNLA051).

### 8.3.4 Probing LVDS Transmission Lines

Always use high impedance (> 100 k $\Omega$ ), low capacitance (< 2 pF) scope probes with a wide bandwidth (1 GHz) scope. Improper probing will give deceiving results.



#### 8.3.5 Cables and Connectors, General Comments

When choosing cable and connectors for LVDS, it is important to remember:

- Use controlled impedance media. The cables and connectors used should have a matched differential impedance of about 100  $\Omega$ . They should not introduce major impedance discontinuities.
- Balanced cables (that is, twisted-pair) are usually better than unbalanced cables (ribbon cable, simple coax)
  for noise reduction and signal quality. Balanced cables tend to generate less EMI due to field canceling
  effects and also tend to pick up electromagnetic radiation and common-mode (not differential mode) noise
  rejected by the receiver.
- For cable distances < 0.5 M, most cables can be made to work effectively. For distances 0.5 M ≤ d ≤ 10 M, CAT 3 (category 3) twisted-pair cable works well, and this cable is readily available and relatively inexpensive.</li>

#### 8.4 Device Functional Modes

The device has one mode of operation that applies when operated within the *Recommended Operating Conditions*.

### 9 Application and Implementation

#### **NOTE**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The DS90LT012AH device is a single-channel LVDS receiver. The functionality of this device is simple, yet extremely flexible, leading to its use in designs ranging from wireless base stations to desktop computers. The varied class of potential applications share features and applications are discussed in the *Typical Application* section.

#### 9.2 Typical Application

### 9.2.1 Point-to-Point Communications

The most basic application for LVDS buffers, as found in this data sheet, is for point-to-point communications of digital data shown in Figure 12.

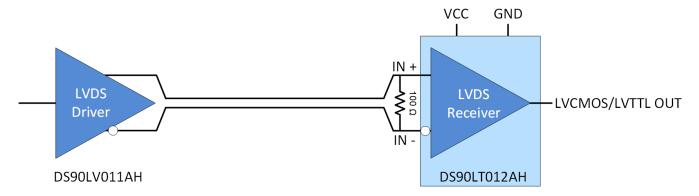


Figure 12. Typical Application



#### **Typical Application (continued)**

A point-to-point communications channel has a single transmitter (driver) and a single receiver. This communications topology is often referred to as simplex. In Figure 12, the driver receives a single-ended input signal and the receiver outputs a single-ended recovered signal. The LVDS driver converts the single-ended input to a differential signal for transmission over a balanced interconnecting media of  $100-\Omega$  characteristic impedance. The conversion from a single-ended signal to an LVDS signal retains the digital data payload while translating to a signal whose features are more appropriate for communication over extended distances or in a noisy environment.

#### 9.2.1.1 Design Requirements

Table 2 lists the design parameters for this example.

**DESIGN PARAMETERS EXAMPLE VALUE** Receiver Supply Voltage (V<sub>CC</sub>) 3 to 3.6 V Receiver Output Voltage 0 to 3.6 V Signaling Rate 0 to 400 Mbps Interconnect Characteristic Impedance  $100 \Omega$ Termination Resistance 100  $\Omega$ 1 Number of Receiver Nodes Ground shift between driver and receiver ±1 V

**Table 2. Design Parameters** 

#### 9.2.1.2 Detailed Design Procedure

#### 9.2.1.2.1 Receiver Bypass Capacitance

Bypass capacitors play a key role in power distribution circuitry. Specifically, they create low-impedance paths between power and ground. At low frequencies, a good digital power supply offers very low-impedance paths between its terminals. However, as higher frequency currents propagate through power traces, the source is quite often incapable of maintaining a low-impedance path to ground. Bypass capacitors are used to address this shortcoming. Usually, large bypass capacitors (10  $\mu F$  to 1000  $\mu F$ ) at the board-level do a good job up into the kHz range. Due to their size and length of their leads, they tend to have large inductance values at the switching frequencies of modern digital circuitry. To solve this problem, one must resort to the use of smaller capacitors (nF to  $\mu F$  range) installed locally next to the integrated circuit.

Multilayer ceramic chip or surface-mount capacitors (size 0603 or 0805) minimize lead inductances of bypass capacitors in high-speed environments, because their lead inductance is about 1 nH. For comparison purposes, a typical capacitor with leads has a lead inductance around 5 nH.

The value of the bypass capacitors used locally with LVDS chips can be determined by Equation 1 and Equation 2 according to Johnson<sup>(1)</sup> equations 8.18 to 8.21. A conservative rise time of 200 ps and a worst-case change in supply current of 1 A covers the whole range of LVDS devices offered by Texas Instruments. In this example, the maximum power supply noise tolerated is 200 mV. However, this figure varies depending on the noise budget available in the design. <sup>(1)</sup>

$$C_{\text{chip}} = \left(\frac{\Delta I_{\text{Maximum Step Change Supply Current}}}{\Delta V_{\text{Maximum Power Supply Noise}}}\right) \times T_{\text{Rise Time}} \tag{1}$$

$$C_{\text{LVDS}} = \left(\frac{1A}{0.2V}\right) \times 200 \text{ ps} = 0.001 \,\mu\text{F} \tag{2}$$

Figure 13 lowers lead inductance and covers intermediate frequencies between the board-level capacitor (>10  $\mu$ F) and the value of capacitance found above (0.001  $\mu$ F). TI recommends that the user place the smallest value of capacitance as close to the chip as possible.

Howard Johnson & Martin Graham. 1993. High Speed Digital Design – A Handbook of Black Magic. Prentice Hall PRT. ISBN number 013395724.



Figure 13. Recommended LVDS Bypass Capacitor Layout

#### 9.2.1.2.2 Interconnecting Media

The physical communication channel between the driver and the receiver may be any balanced and paired metal conductors meeting the requirements of the LVDS standard, the key points of which are included here. This media may be a twisted-pair, twinax, flat ribbon cable, or PCB traces.

The nominal characteristic impedance of the interconnect should be between 100  $\Omega$  and 120  $\Omega$  with a variation of no more than 10% (90  $\Omega$  to 132  $\Omega$ ).

#### 9.2.1.2.3 PCB Transmission Lines

As per the LVDS Owner's Manual Design Guide, 4th Edition (SNLA187), Figure 14 depicts several transmission line structures commonly used in printed-circuit boards (PCBs). Each structure consists of a signal line and return path with a uniform cross section along its length. A microstrip is a signal trace on the top (or bottom) layer, separated by a dielectric layer from its return path in a ground or power plane. A stripline is a signal trace in the inner layer, with a dielectric layer in between a ground plane above and below the signal trace. The dimensions of the structure along with the dielectric material properties determine the characteristic impedance of the transmission line (also called controlled-impedance transmission line).

When two signal lines are placed close by, they form a pair of coupled transmission lines. Figure 14 shows examples of edge-coupled microstrip lines, and edge-coupled or broad-side-coupled striplines. When excited by differential signals, the coupled transmission line is referred to as a differential pair. The characteristic impedance of each line is called odd-mode impedance. The sum of the odd-mode impedances of each line is the differential impedance of the differential pair. In addition to the trace dimensions and dielectric material properties, the spacing between the two traces determines the mutual coupling and impacts the differential impedance. When the two lines are immediately adjacent; for example, S is less than 2 W, the differential pair is called a tightly-coupled differential pair. To maintain constant differential impedance along the length, it is important to keep the trace width and spacing uniform along the length, as well as maintain good symmetry between the two lines.

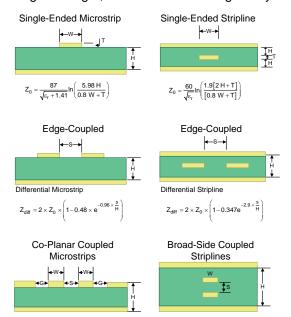


Figure 14. Controlled-Impedance Transmission Lines



# 9.2.1.3 Application Curve

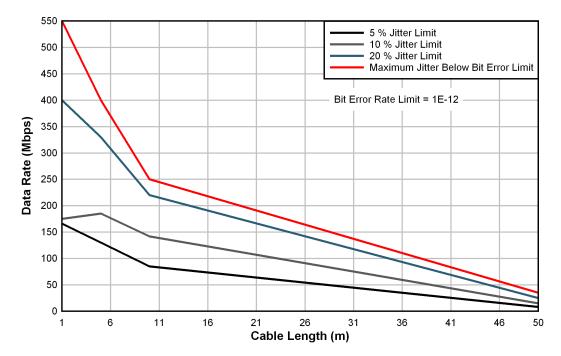


Figure 15. DS90LT012AH Performance: Cable Length vs Data Rate



### 10 Power Supply Recommendations

#### 10.1 Power Supply Considerations

The DS90LT012AH driver is designed to operate from a single power supply with the supply voltage range of 3 V to 3.6 V. In a typical application, a driver and a receiver may be on separate boards, or even separate equipment. In these cases, separate supplies would be used at each location. The expected ground potential difference between the driver power supply and the receiver power supply would be less than |±1 V|. Board level and local device level bypass capacitance should be used.

### 11 Layout

#### 11.1 Layout Guidelines

#### 11.1.1 Microstrip vs. Stripline Topologies

As per the *LVDS Application and Data Handbook* (SLLD009), printed-circuit boards usually offer designers two transmission line options: Microstrip and stripline. Microstrips are traces on the outer layer of a PCB, as shown in Figure 16.

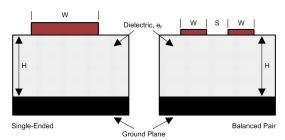


Figure 16. Microstrip Topology

On the other hand, striplines are traces between two ground planes. Striplines are less prone to emissions and susceptibility problems because the reference planes effectively shield the embedded traces. However, from the standpoint of high-speed transmission, juxtaposing two planes creates additional capacitance. TI recommends routing LVDS signals on microstrip transmission lines when possible. The PCB traces allow designers to specify the necessary tolerances for  $Z_O$  based on the overall noise budget and reflection allowances. Footnotes 1<sup>(2)</sup>, 2<sup>(3)</sup>, and 3<sup>(4)</sup> provide formulas for  $Z_O$  and  $t_{PD}$  for differential and single-ended traces. (2) (3) (4)

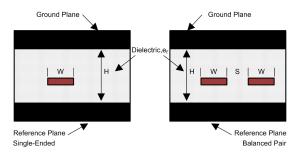


Figure 17. Stripline Topology

<sup>(2)</sup> Howard Johnson & Martin Graham.1993. High Speed Digital Design – A Handbook of Black Magic. Prentice Hall PRT. ISBN number 013395724

<sup>(3)</sup> Mark I. Montrose. 1996. Printed Circuit Board Design Techniques for EMC Compliance. IEEE Press. ISBN number 0780311310.

<sup>(4)</sup> Clyde F. Coombs, Jr. Ed, Printed Circuits Handbook, McGraw Hill, ISBN number 0070127549.



#### 11.1.2 Dielectric Type and Board Construction

The speeds at which signals travel across the board dictates the choice of dielectric. FR-4, or equivalent, usually provides adequate performance for use with LVDS signals. If rise or fall times of LVCMOS/LVTTL signals are less than 500 ps, empirical results indicate that a material with a dielectric constant near 3.4, such as Rogers<sup>™</sup> 4350 or Nelco N4000-13 is better suited. Once the designer chooses the dielectric, there are several parameters pertaining to the board construction that can affect performance. The following set of guidelines were developed experimentally through several designs involving LVDS devices:

- Copper weight: 15 g or 1/2 oz start, plated to 30 g or 1 oz
- All exposed circuitry should be solder-plated (60/40) to 7.62 μm or 0.0003 in (minimum).
- Copper plating should be 25.4 μm or 0.001 in (minimum) in plated-through-holes.
- Solder mask over bare copper with solder hot-air leveling

#### 11.1.3 Recommended Stack Layout

Following the choice of dielectrics and design specifications, the designer must decide how many levels to use in the stack. To reduce the LVCMOS/LVTTL to LVDS crosstalk, it is good practice to have at least two separate signal planes as shown in Figure 18.

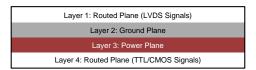


Figure 18. Four-Layer PCB Board

#### NOTE

The separation between layers 2 and 3 should be 127  $\mu m$  (0.005 in). By keeping the power and ground planes tightly coupled, the increased capacitance acts as a bypass for transients.

One of the most common stack configurations is the six-layer board, as shown in Figure 19.

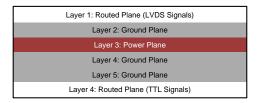


Figure 19. Six-Layer PCB Board

In this particular configuration, it is possible to isolate each signal layer from the power plane by at least one ground plane. The result is improved signal integrity, but fabrication is more expensive. Using the 6-layer board is preferable, because it offers the layout designer more flexibility in varying the distance between signal layers and referenced planes in addition to ensuring reference to a ground plane for signal layers 1 and 6.

#### 11.1.4 Separation Between Traces

The separation between traces depends on several factors, but the amount of coupling that can be tolerated usually dictates the actual separation. Low-noise coupling requires close coupling between the differential pair of an LVDS link to benefit from the electromagnetic field cancellation. The traces should be  $100-\Omega$  differential and thus coupled in the manner that best fits this requirement. In addition, differential pairs should have the same electrical length to ensure that they are balanced, thus minimizing problems with skew and signal reflection.

In the case of two adjacent single-ended traces, one should use the 3-W rule: the distance between two traces must be greater than two times the width of a single trace, or three times its width measured from trace center to trace center. This increased separation effectively reduces the potential for crosstalk. The same rule should be applied to the separation between adjacent LVDS differential pairs, whether the traces are edge-coupled or broad-side-coupled.

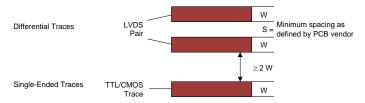


Figure 20. 3-W Rule for Single-Ended and Differential Traces (Top View)

Exercise caution when using autorouters, because they do not always account for all factors affecting crosstalk and signal reflection. For instance, it is best to avoid sharp 90° turns to prevent discontinuities in the signal path. Using successive 45° turns tends to minimize reflections.

#### 11.1.5 Crosstalk and Ground Bounce Minimization

To reduce crosstalk, it is important to provide a return path to high-frequency currents that is as close to its originating trace as possible. A ground plane usually achieves this. Because the returning currents always choose the path of lowest inductance, they are most likely to return directly under the original trace, thus minimizing crosstalk. Lowering the area of the current loop lowers the potential for crosstalk. Traces kept as short as possible with an uninterrupted ground plane running beneath them emit the minimum amount of electromagnetic field strength. Discontinuities in the ground plane increase the return path inductance and should be avoided.

#### 11.1.6 Decoupling

Each power or ground lead of a high-speed device should be connected to the PCB through a low inductance path. For best results, one or more vias are used to connect a power or ground pin to the nearby plane. TI recommends placing a via immediately adjacent to the pin to avoid adding trace inductance. Placing a power plane closer to the top of the board reduces the effective via length and its associated inductance.

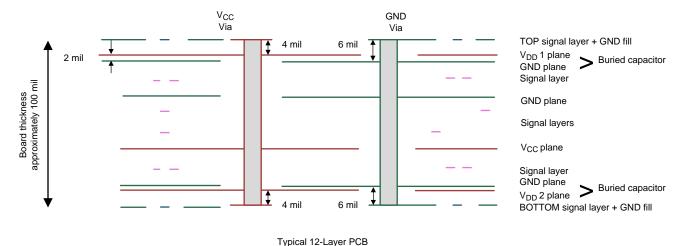


Figure 21. Low Inductance, High-Capacitance Power Connection



Bypass capacitors should be placed close to  $V_{DD}$  pins. They can be placed conveniently near the corners or underneath the package to minimize the loop area. This extends the useful frequency range of the added capacitance. Small-physical-size capacitors, such as 0402 or even 0201, or X7R surface-mount capacitors should be used to minimize body inductance of capacitors. Each bypass capacitor is connected to the power and ground plane through vias tangent to the pads of the capacitor as shown in Figure 22(a).

An X7R surface-mount capacitor of size 0402 has about 0.5 nH of body inductance. At frequencies above 30 MHz or so, X7R capacitors behave as low-impedance inductors. To extend the operating frequency range to a few hundred MHz, an array of different capacitor values like 100 pF, 1 nF, 0.03 μF, and 0.1 μF are commonly used in parallel. The most effective bypass capacitor can be built using sandwiched layers of power and ground at a separation of 2 to 3 mils. With a 2-mil FR4 dielectric, there is approximately 500 pF per square inch of PCB. Refer back to Figure 14 for some examples. Many high-speed devices provide a low-inductance GND connection on the backside of the package. This center dap must be connected to a ground plane through an array of vias. The via array reduces the effective inductance to ground and enhances the thermal performance of the small Surface Mount Technology (SMT) package. Placing vias around the perimeter of the dap connection ensures proper heat spreading and the lowest possible die temperature. Placing high-performance devices on opposing sides of the PCB using two GND planes (as shown in Figure 14) creates multiple paths for heat transfer. Often thermal PCB issues are the result of one device adding heat to another, resulting in a very high local temperature. Multiple paths for heat transfer minimize this possibility. In many cases the GND dap that is so important for heat dissipation makes the optimal decoupling layout impossible to achieve due to insufficient padto-dap spacing as shown in Figure 22(b). When this occurs, placing the decoupling capacitor on the backside of the board keeps the extra inductance to a minimum. It is important to place the V<sub>DD</sub> via as close to the device pin as possible while still allowing for sufficient solder mask coverage. If the via is left open, solder may flow from the pad and into the via barrel. This will result in a poor solder connection.



Figure 22. Typical Decoupling Capacitor Layouts

At least two or three times the width of an individual trace should separate single-ended traces and differential pairs to minimize the potential for crosstalk. Single-ended traces that run in parallel for less than the wavelength of the rise or fall times usually have negligible crosstalk. Increase the spacing between signal paths for long parallel runs to reduce crosstalk. Boards with limited real estate can benefit from the staggered trace layout, as shown in Figure 23.

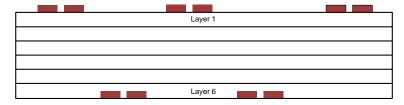


Figure 23. Staggered Trace Layout

This configuration lays out alternating signal traces on different layers. Thus, the horizontal separation between traces can be less than 2 or 3 times the width of individual traces. To ensure continuity in the ground signal path, TI recommends having an adjacent ground via for every signal via, as shown in Figure 24. Note that vias create additional capacitance. For example, a typical via has a lumped capacitance effect of 1/2 pF to 1 pF in FR4.



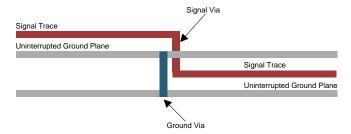


Figure 24. Ground Via Location (Side View)

Short and low-impedance connection of the device ground pins to the PCB ground plane reduces ground bounce. Holes and cutouts in the ground planes can adversely affect current return paths if they create discontinuities that increase returning current loop areas.

To minimize EMI problems, TI recommends avoiding discontinuities below a trace (for example, holes, slits, and so on) and keeping traces as short as possible. Zoning the board wisely by placing all similar functions in the same area, as opposed to mixing them together, helps reduce susceptibility issues.

#### 11.2 Layout Example

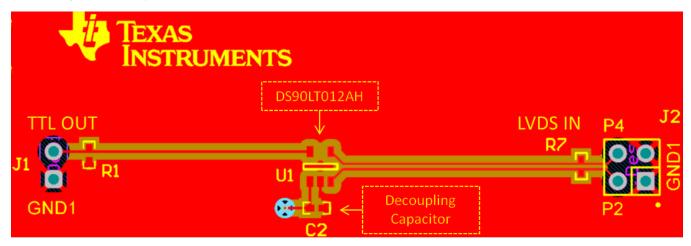


Figure 25. Example DS90LT012AH Layout



#### 12 器件和文档支持

#### 12.1 接收文档更新通知

要接收文档更新通知,请导航至 Tl.com.cn 上的器件产品文件夹。单击右上角的*通知我* 进行注册,即可每周接收产 品信息更改摘要。有关更改的详细信息,请查看任何已修订文档中包含的修订历史记录。

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🗱 ESD 的损坏小至导致微小的性能降级,大至整个器件故障。 精密的集成电路可能更容易受到损坏,这是因为非常细微的参数更改都可 能会导致器件与其发布的规格不相符。

#### 12.5 术语表

SLYZ022 — TI 术语表。

这份术语表列出并解释术语、缩写和定义。

### 13 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更,恕不另行通知,且 不会对此文档进行修订。如需获取此数据表的浏览器版本,请查阅左侧的导航栏。

www.ti.com 10-Nov-2025

#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
DS90LT012AHMF/NOPB	Active	Production	SOT-23 (DBV)   5	1000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	N05
DS90LT012AHMF/NOPB.A	Active	Production	SOT-23 (DBV)   5	1000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	N05

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

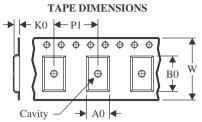
<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS90LT012AHMF/NOPB	SOT-23	DBV	5	1000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
DS90LT012AHMF/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

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### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS90LT012AHMF/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
DS90LT012AHMF/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0



SMALL OUTLINE TRANSISTOR



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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